

CMSD7000

**SURFACE MOUNT
DUAL, IN SERIES
SILICON SWITCHING DIODES**



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMSD7000 type is a ultra-high speed silicon switching diodes manufactured by the epitaxial planar process, in an epoxy molded super-mini surface mount package, connected in a series configuration, designed for high speed switching applications.

MARKING CODE: 5CC

MAXIMUM RATINGS: ($T_A = 25^\circ\text{C}$)

Peak Repetitive Reverse Voltage
Average Forward Current
Peak Forward Current, $t_p=1.0s$
Power Dissipation
Operating and Storage Junction Temperature
Thermal Resistance

SYMBOL

V_{RRM} 100
 I_O 200
 I_{FM} 500
 P_D 275
 T_J, T_{stg} -65 to +150
 θ_{JA} 455

UNITS

V
mA
mA
mW
 $^\circ\text{C}$
 $^\circ\text{C/W}$

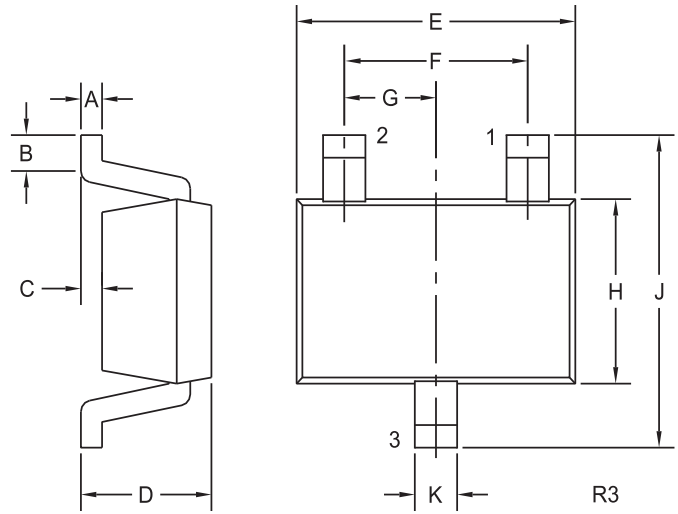
ELECTRICAL CHARACTERISTICS PER DIODE: ($T_A = 25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_R	$V_R=50V$			300	nA
I_R	$V_R=50V, T_A=125^\circ\text{C}$			100	μA
I_R	$V_R=100V$			500	nA
BV_R	$I_R=100\mu\text{A}$	100			V
V_F	$I_F=1.0\text{mA}$	0.55		0.70	V
V_F	$I_F=10\text{mA}$	0.67		0.82	V
V_F	$I_F=100\text{mA}$	0.75		1.10	V
C_T	$V_R=0, f=1.0\text{MHz}$		1.5	2.6	pF
t_{rr}	$I_R=I_F=10\text{mA}, I_{rr}=1.0\text{mA}, R_L=100\Omega$		2.0	4.0	ns

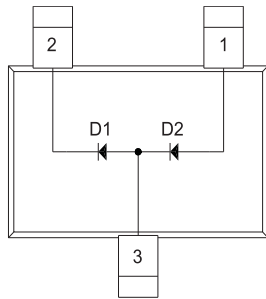
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SOT-323 CASE - MECHANICAL OUTLINE



PIN CONFIGURATION



LEAD CODE:

- 1) Anode D2
- 2) Cathode D1
- 3) Anode D1, Cathode D2

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SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.002	0.008	0.05	0.20
B	0.004	-	0.10	-
C	-	0.004	-	0.10
D	0.031	0.043	0.80	1.10
E	0.071	0.087	1.80	2.20
F	0.051		1.30	
G	0.026		0.65	
H	0.045	0.053	1.15	1.35
J	0.079	0.087	2.00	2.20
K	0.008	0.016	0.20	0.40

SOT-323 (REV: R3)

R4 (8-February 2010)